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Zhenan Bao
David J. Gundlach
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Contents

vii *Conference Committee*

SESSION 1 **CIRCUITS AND DISPLAYS**

- 6658 02 **Capacitance-voltage characteristics of organic thin-film transistors (Invited Paper)** [6658-01]
G. H. Gelinck, TNO (Netherlands); E. van Veenendaal, Polymer Vision (Netherlands);
H. van der Vegte, R. Coehoorn, Philips Research (Netherlands)
- 6658 03 **Organic thin-film transistor arrays for active-matrix organic light emitting diode (Invited Paper)** [6658-02]
S. Lee, H. Moon, D. H. Kim, B.-W. Koo, E.-J. Jeong, B.-L. Lee, J.-Y. Kim, E. Lee, K.-M. Hahn,
J.-S. Han, J.-I. Park, J.-B. Seon, J.-W. Kim, Y.-T. Chun, S. Kim, S. K. Kang, Samsung Advanced
Institute of Technology (South Korea)
- 6658 04 **13.56 MHz polymer rectifier by printing processes (Invited Paper)** [6658-03]
C.-Y. Lin, C.-H. Chou, J. Hou, Y.-J. Chan, Industrial Technology Research Institute (Taiwan)

SESSION 2 **GATE DIELECTRICS AND CONTACTS**

- 6658 07 **High performance organic field-effect transistors with fluoropolymer gate dielectric** [6658-06]
W. L. Kalb, T. Mathis, S. Haas, A. F. Stassen, B. Batlogg, ETH Zürich (Switzerland)

SESSION 3 **CHARGE TRANSPORT**

- 6658 0C **Determination of the density of trap states in organic thin film transistors** [6658-11]
F. Yan, The Hong Kong Polytechnic Univ. (Hong Kong China)
- 6658 0D **Charge transport mechanisms in organic and microcrystalline silicon field-effect transistors (Invited Paper)** [6658-12]
S. J. Konezny, École Polytechnique Fédérale de Lausanne (Switzerland); M. N. Bussac, Ctr.
de Physique Théorique, CNRS, École Polytechnique (France); A. Geiser, L. Zuppiroli, École
Polytechnique Fédérale de Lausanne (Switzerland)
- 6658 0E **Current conduction in ambipolar organic field-effect transistors (OFETs)** [6658-13]
H. L. Kwok, Univ. of Victoria (Canada)

SESSION 4 ORGANIC CRYSTALS

- 6658 OG **Modification of charge transport in single crystal rubrene (Invited Paper)** [6658-15]
O. Mitrofanov, Alcatel-Lucent (USA); D. V. Lang, Columbia Univ. (USA); T. Siegrist, Alcatel-Lucent (USA); W.-Y. So, Columbia Univ. (USA); C. Kloc, A. P. Ramirez, Alcatel-Lucent (USA)

SESSION 5 MOLECULAR DESIGN

- 6658 OL **Crystal design for organic semiconductors: the effects of substitution on crystal packing (Invited Paper)** [6658-20]
J. E. Anthony, B. Purushothaman, Univ. of Kentucky (USA)
- 6658 ON **High performance n-type FETs based on heterocyclic ring systems with trifluoromethylphenyl groups (Invited Paper)** [6658-22]
Y. Yamashita, S. Shimono, T. Kono, D. Kumaki, J. Nishida, Tokyo Institute of Technology (Japan); S. Tokito, NHK Science and Technical Research Labs. (Japan)

SESSION 6 OTFTs I

- 6658 OP **Microstructural mobility of the polymeric gate insulator affecting pentacene charge transport (Invited Paper)** [6658-05]
A. Facchetti, C. Kim, T. J. Marks, Northwestern Univ. (USA)
- 6658 OR **Organic phototransistor behavior and light-accelerated bias stress** [6658-26]
M. Debucquoy, IMEC (Belgium) and Katholieke Univ. Leuven (Belgium); S. Verlaak, IMEC (Belgium); S. Stoedel, IMEC (Belgium) and Katholieke Univ. Leuven (Belgium); K. Myny, J. Genoe, IMEC (Belgium); P. Heremans, IMEC (Belgium) and Katholieke Univ. Leuven (Belgium)
- 6658 OS **High mobility solution-processed n-channel organic thin film transistors** [6658-27]
H. Yan, Polyera Corp. (USA); S. Lu, Northwestern Univ. (USA); Y. Zheng, P. Inagaki, Polyera Corp. (USA); A. Facchetti, T. J. Marks, Northwestern Univ. (USA)
- 6658 OT **High performance organic field-effect transistors using high- κ dielectrics grown by atomic layer deposition (ALD)** [6658-28]
X.-H. Zhang, B. Domercq, X. Wang, S. Yoo, T. Kondo, Z. L. Wang, B. Kippelen, Georgia Institute of Technology (USA)

SESSION 7 OTFTs II

- 6658 OV **Distinguishing between nonlinear channel transport and contact effects in organic FETs** [6658-30]
B. H. Hamadani, J. L. LeBoeuf, R. J. Kline, National Institute of Standards and Technology (USA); I. McCulloch, M. Heeney, Merck Chemicals (United Kingdom); C. A. Richter, L. J. Richter, D. J. Gundlach, National Institute of Standards and Technology (USA)

6658 0W **Dielectric interface modification by UV irradiation: a novel method to control OFET charge carrier transport properties** [6658-31]
N. Benson, M. Schidleja, C. Siol, C. Melzer, H. von Seggern, Univ. of Technology Darmstadt (Germany)

6658 0Y **Transfer printing as a method for fabricating hybrid devices on flexible substrates** [6658-33]
D. R. Hines, A. E. Southard, A. Tunnell, V. Sangwan, T. Moore, J.-H. Chen, M. S. Fuhrer, E. D. Williams, Univ. of Maryland, College Park (USA)

SESSION 8 NOVEL PROCESSING OF SOLUBLE ORGANIC SEMICONDUCTORS

6658 10 **Record high mobilities for regioregular poly(3-octylthiophene) (Invited Paper)** [6658-35]
G. Sauv , J. Liu, R. Zhang, T. Kowalewski, R. D. McCullough, Carnegie Mellon Univ. (USA)

6658 11 **Ink-jet printing of self-aligned soluble-pentacene crystals for high-performance organic field-effect transistors** [6658-36]
J. A. Lim, W. H. Lee, Y. D. Park, H. S. Lee, K. Cho, Pohang Univ. of Science and Technology (South Korea)

6658 12 **Solubility- and temperature-driven thin film structures of polymeric thiophene derivatives for high performance OFET applications** [6658-37]
S. W. LeFevre, Rensselaer Polytechnic Institute (USA); Z. Bao, Stanford Univ. (USA); C. Y. Ryu, R. W. Siegel, H. Yang, Rensselaer Polytechnic Institute (USA)

6658 16 **Performance improvement and evaluation of an all plastic organic field effect transistor** [6658-41]
S. Ochiai, Aichi Institute of Technology (Japan); X. Wang, Consultant (China); N. P. Rajesh, SSN College of Engineering (India); A. Ohashi, K. Kojima, T. Mizutani, Aichi Institute of Technology (Japan)

POSTER SESSION

6658 18 **Synthesis of bis-silylated oligothiophenes for solution-processable organic field effect transistors** [6658-45]
J. H. Choi, D. W. Cho, S.-H. Jin, Pusan National Univ. (South Korea); C. K. Song, Dong-A Univ. (South Korea); U. C. Yoon, Pusan National Univ. (South Korea)

6658 19 **A novel structure of directly patterned isolating layer for organic thin-film transistor-driven organic light emitting diodes** [6658-46]
Y.-K. Wang, T.-H. Lin, J.-Y. Yan, T.-W. Lee, Y.-Y. Shen, S.-T. Yeh, M.-R. Tseng, P.-S. Wu, K.-T. Lin, C.-H. Chen, J.-C. Ho, Industrial Technology Research Institute (Taiwan)

6658 1A **Organic field-effect transistors with solution-processible thiophene/phenylene based-oligomer derivative films** [6658-47]
H. Yang, Rensselaer Polytechnic Institute (USA); J. Locklin, Univ. of Georgia (USA); B. Singh, Johannes Kepler Univ. of Linz (Austria); Z. Bao, Stanford Univ. (USA)

6658 1B **Understanding the mechanisms of photodecarbonylation of the photoprecursors of higher poly(acene)s** [6658-48]
R. Mondal, A. N. Okhrimenko, B. K. Shah, D. C. Neckers, Bowling Green State Univ. (USA)

- 6658 1C **Highly sensitive thin film polymer phototransistors** [6658-49]
X. Wang, K. Wasapinyokul, W. D. Tan, R. Rawcliffe, A. J. Campbell, D. D. C. Bradley, Imperial
College London (United Kingdom)
- 6658 1F **Organic thin-film transistors using suspended source/drain electrode structure** [6658-53]
Y. U. Lee, Y.-H. Kim, J.-I. Han, Korea Electronics Technology Institute (South Korea);
M.-K. Han, Seoul National Univ. (South Korea)

Author Index

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Takao Someya, The University of Tokyo (Japan)

Session Chairs

- 1 Circuits and Displays
Thokchom B. Singh, Johannes Kepler Universität Linz (Austria)
- 2 Gate Dielectrics and Contacts
John E. Anthony, University of Kentucky (USA)
- 3 Charge Transport
David J. Gundlach, National Institute of Standards and Technology (USA)
- 4 Organic Crystals
Daniel A. Moses, University of California, Santa Barbara (USA)
- 5 Molecular Design
Antonio F. Facchetti, Northwestern University (USA)

- 6 OTFTs I
Gerwin H. Gelinck, TNO (Netherlands)
- 7 OTFTs II
Kilwon Cho, Pohang University of Science and Technology (South Korea)
- 8 Novel Processing of Soluble Organic Semiconductors
Gerwin H. Gelinck, TNO (Netherlands)